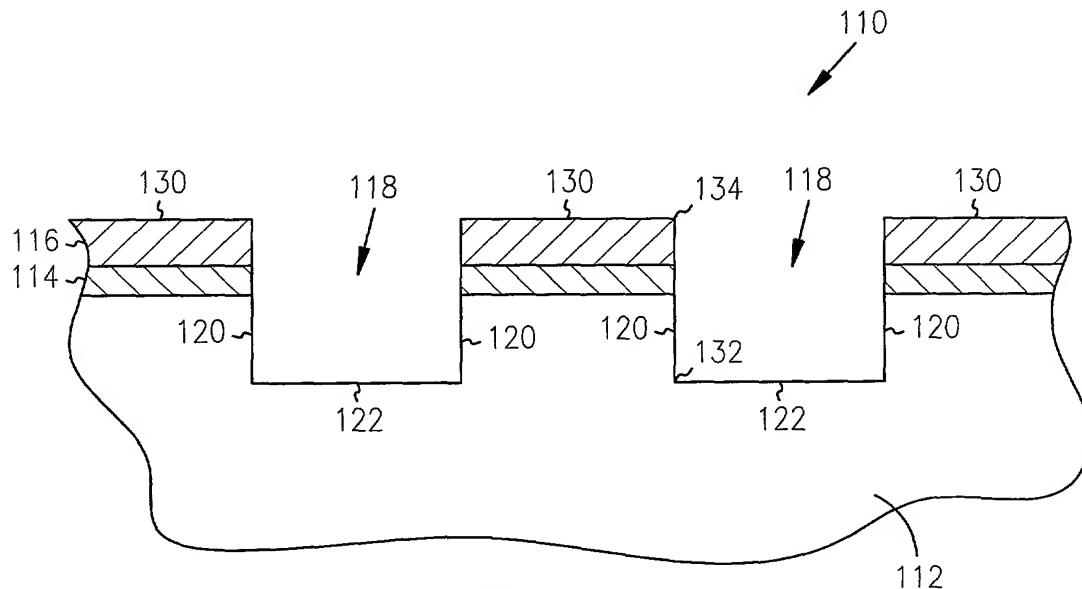
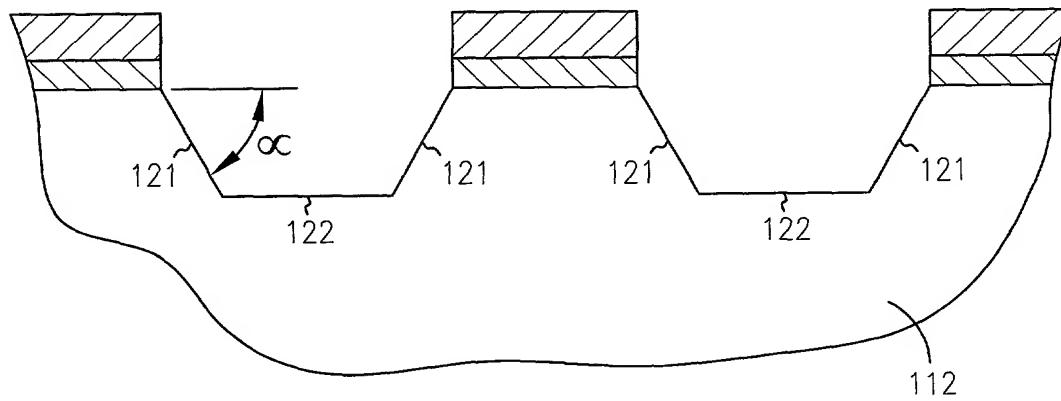


TITLE: TRANSISTOR STRUCTURE HAVING REDUCED TRANSISTOR LEAKAGE ATTRIBUTES  
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**FIG. 1A**  
(PRIOR)



**FIG. 1B**  
(PRIOR)

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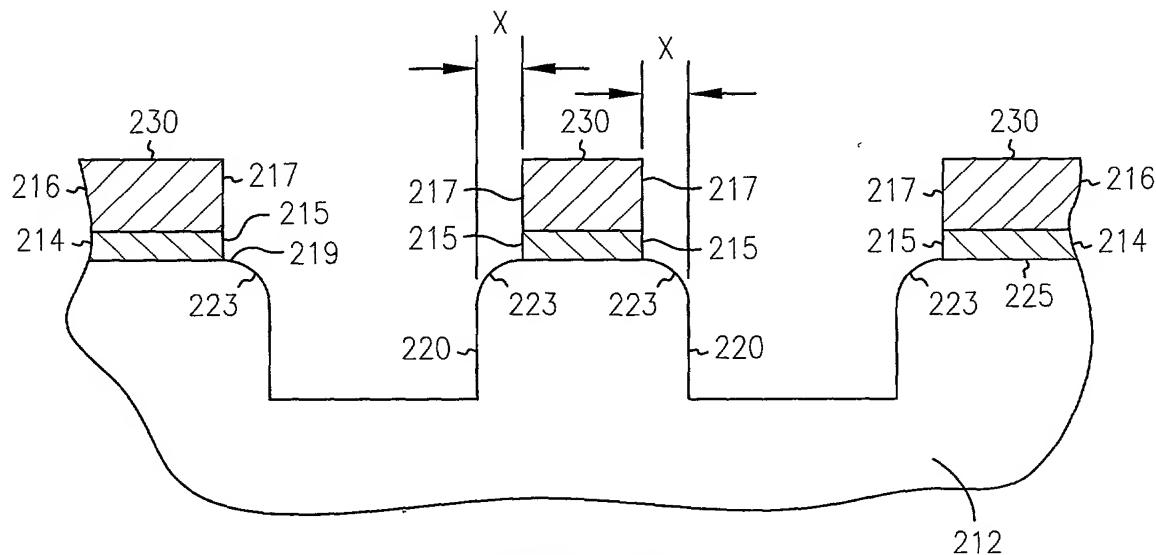


FIG. 2

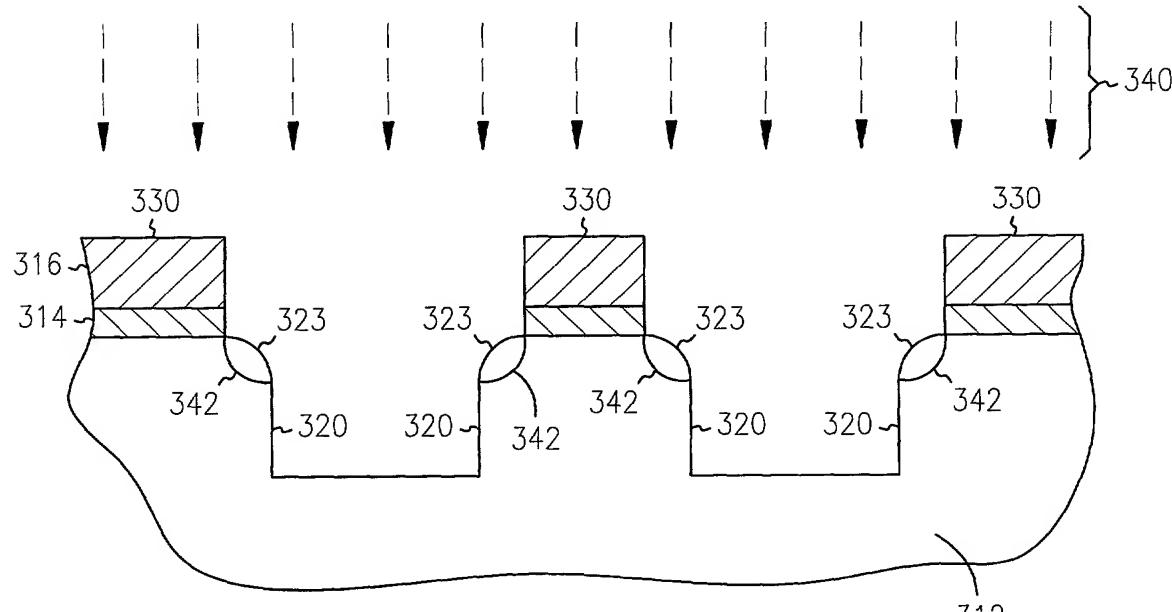


FIG. 3

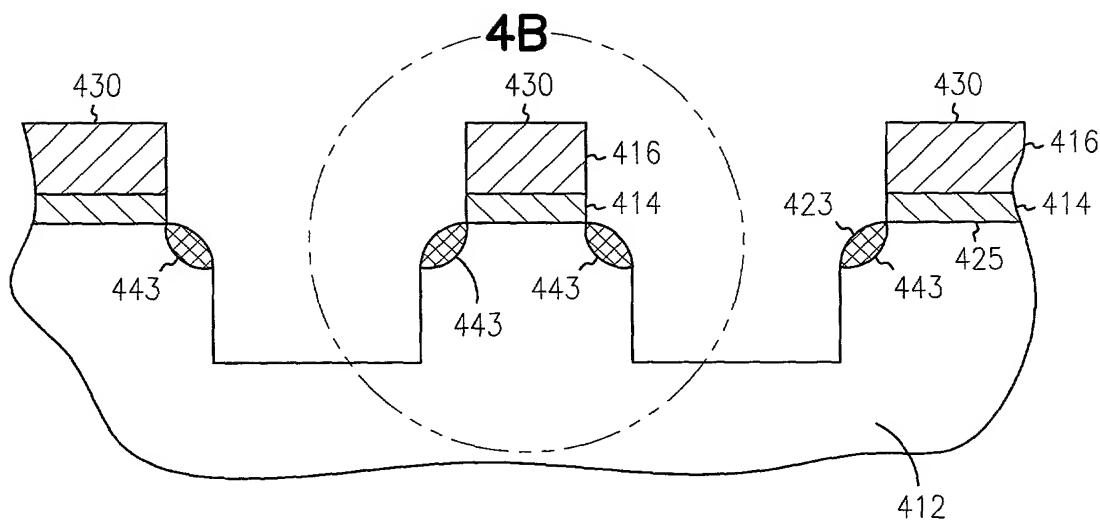


FIG. 4A

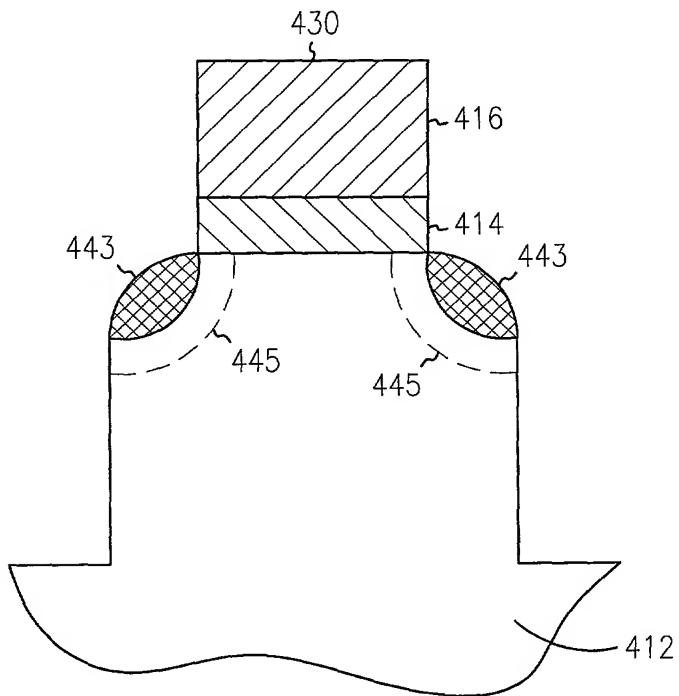


FIG. 4B

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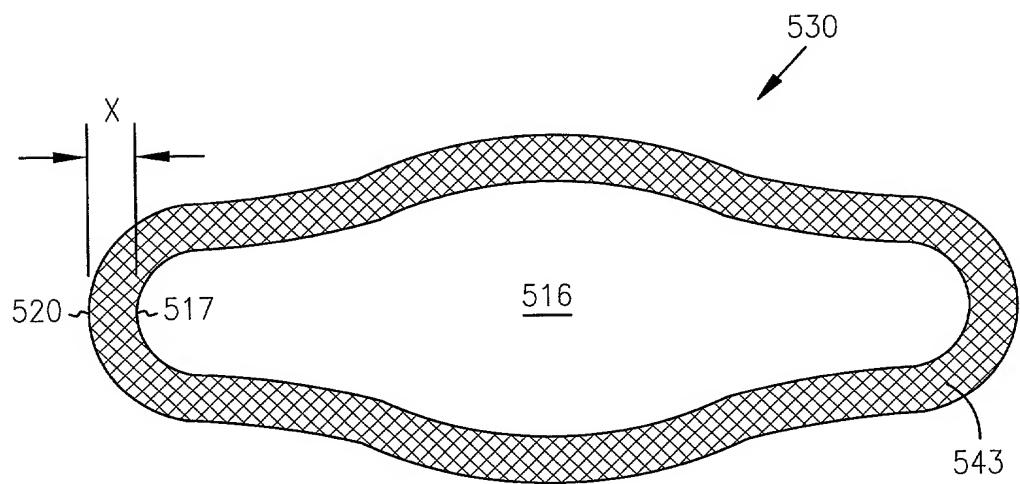


FIG. 5

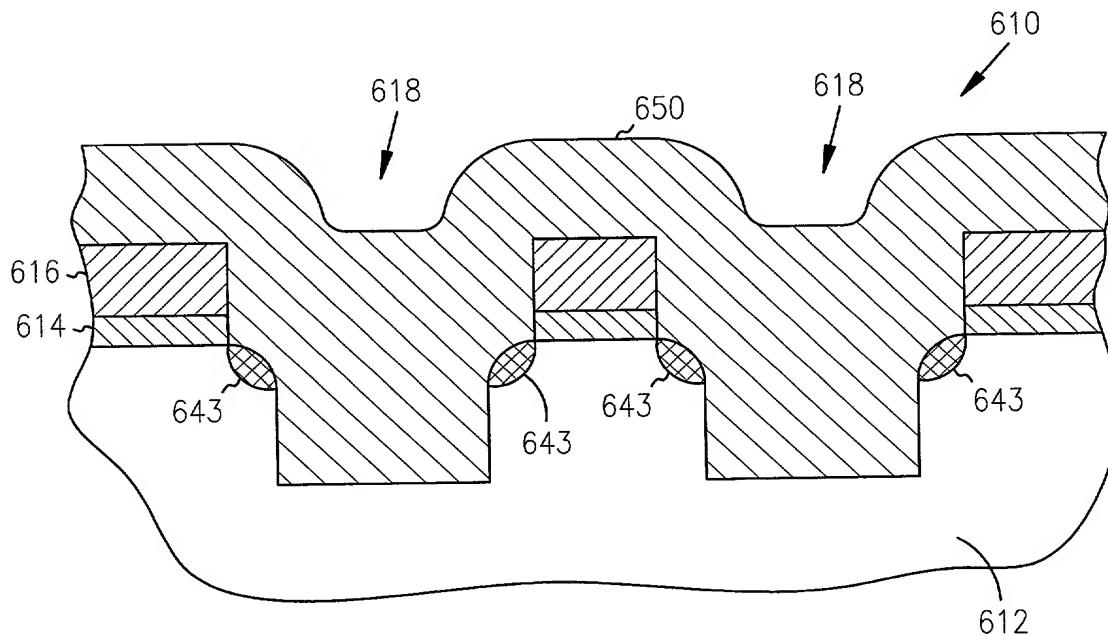


FIG. 6A

10003300-047002

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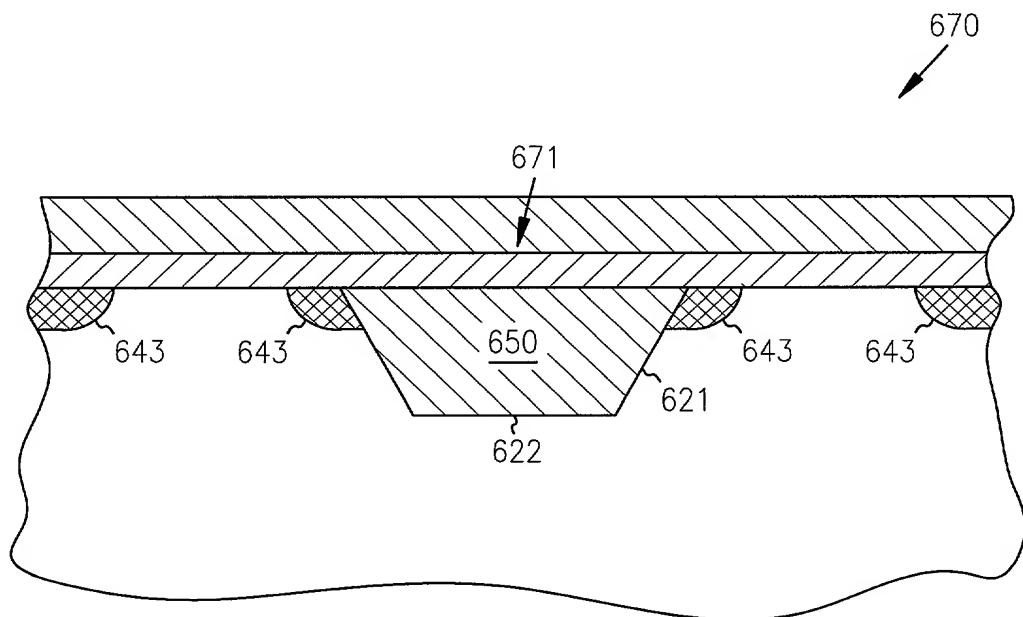


FIG. 6B

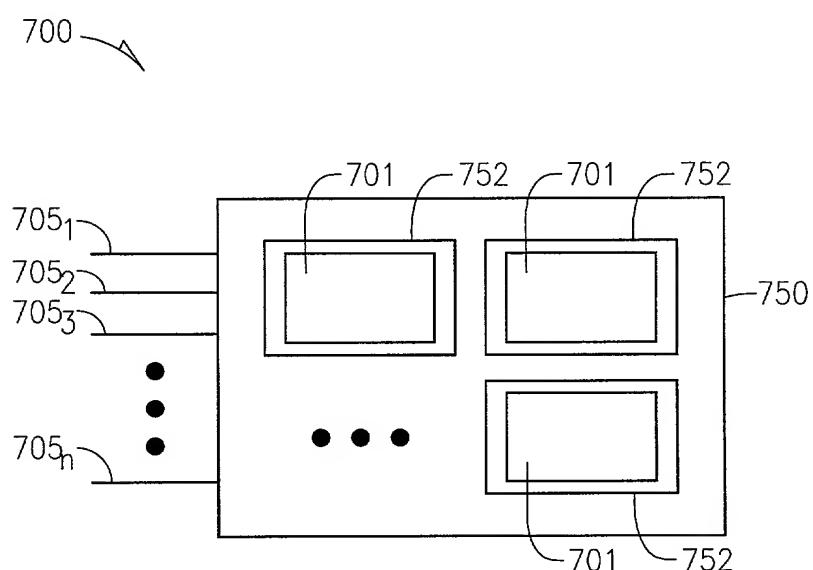


FIG. 7

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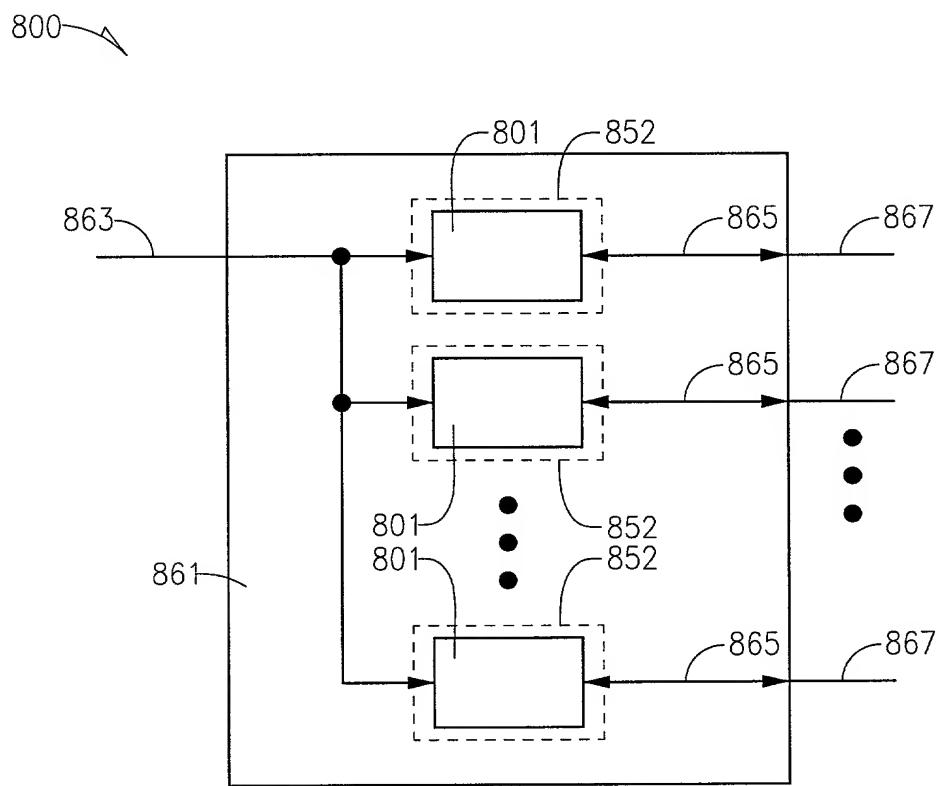


FIG. 8

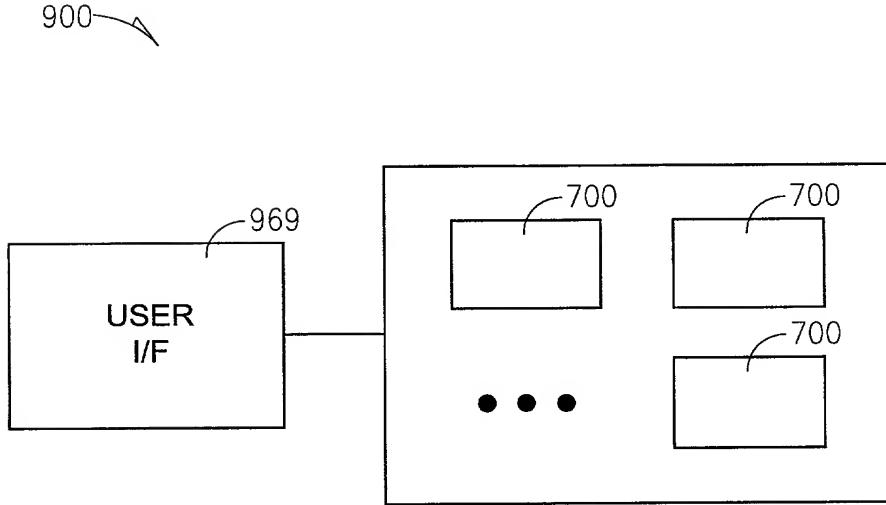


FIG. 9

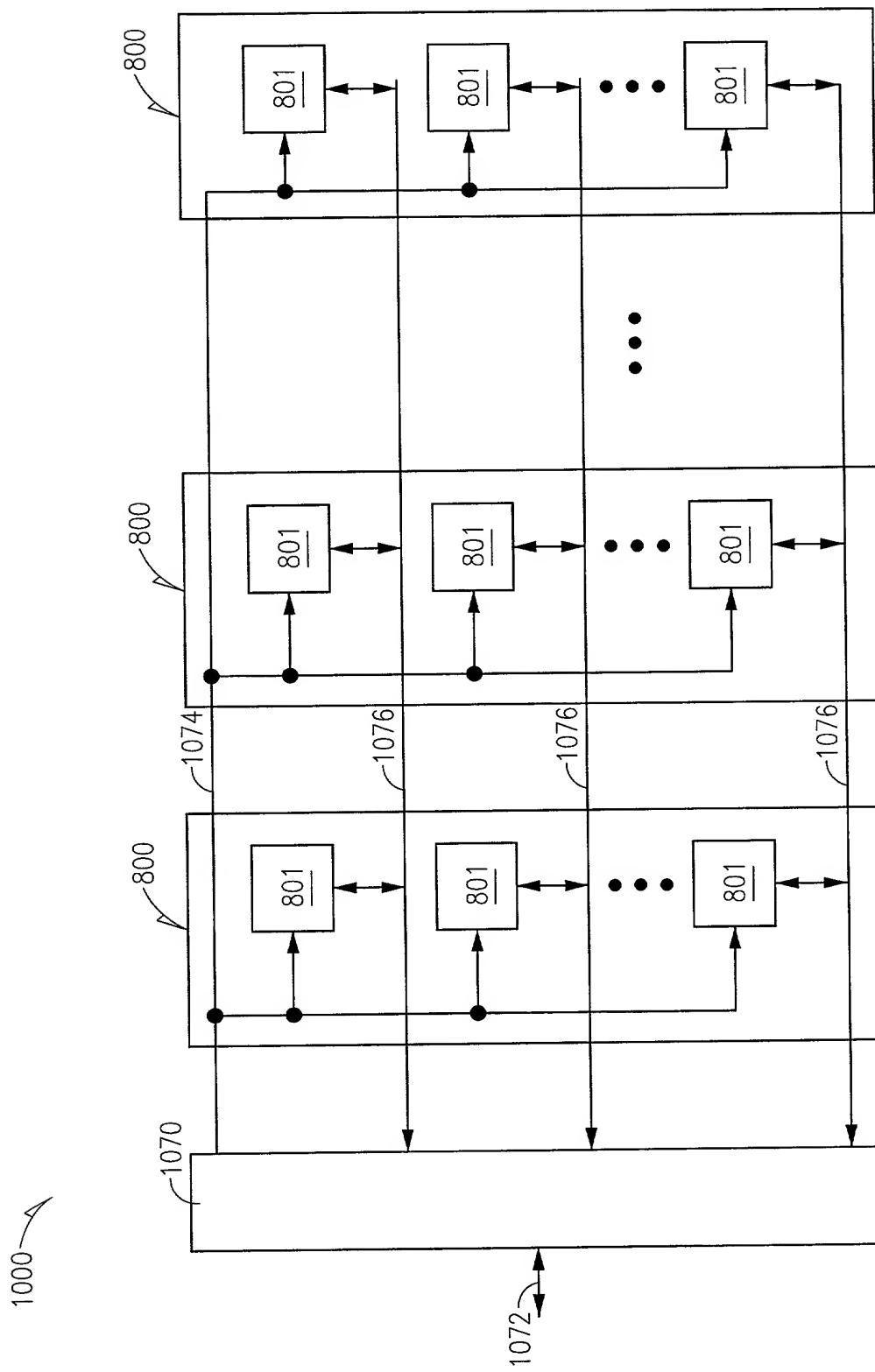


FIG. 10

TITLE: TRANSISTOR STRUCTURE HAVING REDUCED TRANSISTOR LEAKAGE ATTRIBUTES  
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DOCKET NO.: 303.780US1

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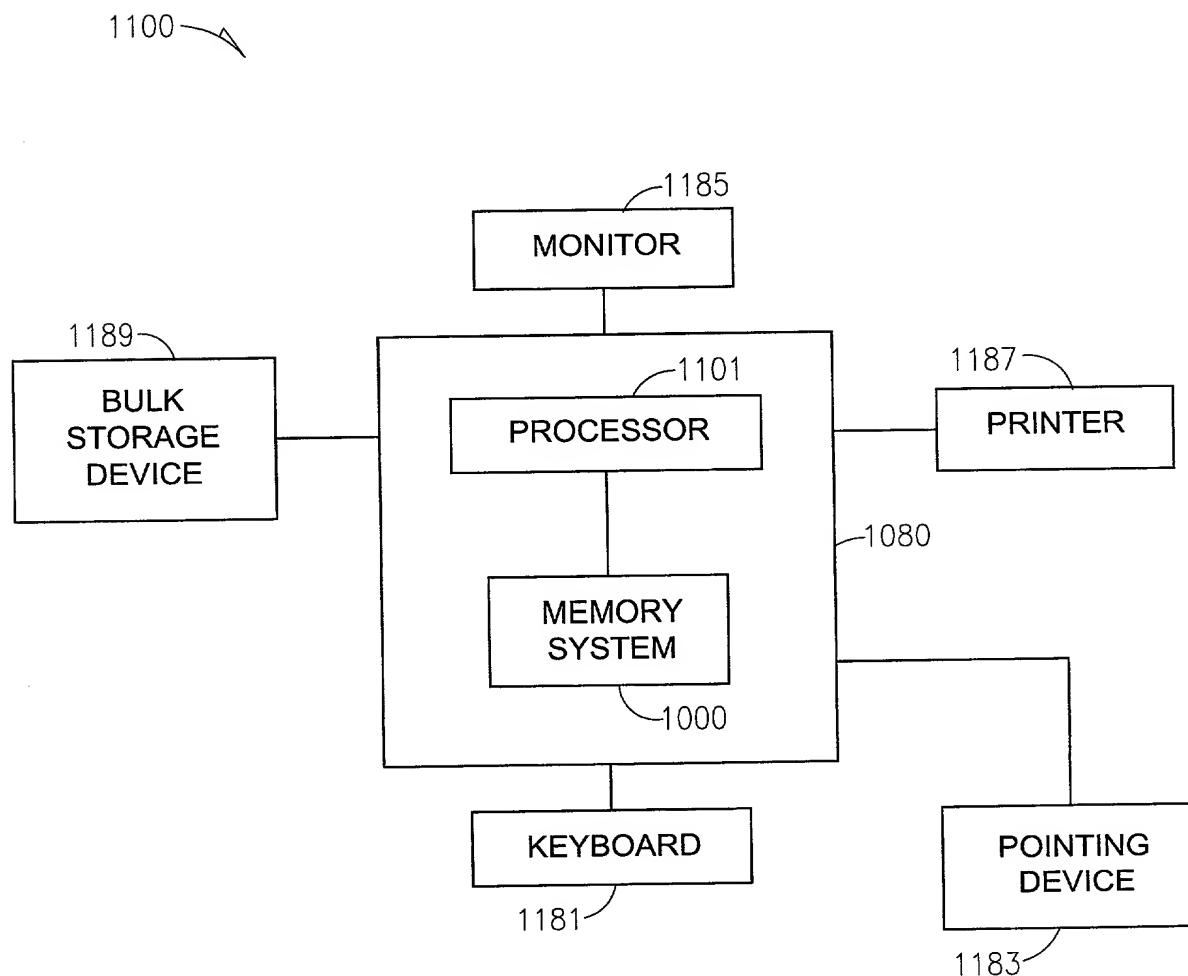


FIG. 11